Docket No.: 49657-962

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

re Application of

Yoshio FUDEYASU

Serial No.: 09/769,417

Group Art Unit: 2187

Filed: January 26, 2001

Examiner: Mehdi NAMAZI

For:

SEMICONDUCTOR MEMORY DEVICE AND MEMORY SYSTEM USING THE SAME

THE COMMISSIONER FOR PATENTS AND TRADEMARKS

Washington, DC 20231

Dear Sir:

RECEIVED

OCT 1 0 2002

No additional fee is required. Applicant is entitled to small entity status under 37 CFR 1.27

Transmitted herewith is an Amendment in the above identified application.

Also attached:

Technology Center 2100

The fee has been calculated as shown below:

	NO. OF CLAIMS	HIGHEST PREVIOUSLY PAID FOR	EXTRA CLAIMS	RATE	FEE
Total Claims	15	20	0	\$18.00 =	\$0.00
Independent Claims	3	3	0	\$84.00 =	\$0.00
-		Multiple claims newly presented			\$0.00
		For for Information Disclosure Statement			\$18Ó.00
					\$0.00
	•	Total of Above Calculations			\$180.00

 \boxtimes Please charge my Deposit Account No. 500417 in the amount of \$180.00. An additional copy of this transmittal sheet is submitted herewith.

The Commissioner is hereby authorized to charge payment of any fees associated with this communication or credit any overpayment, to Deposit Account No. 500417, including any filing fees under 37 CFR 1.16 \boxtimes for presentation of extra claims and any patent application processing fees under 37 CFR 1.17.

Respectfully submitted,

MCDERMOTT, WILL & EMERY

David M. Tennant

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Date: October 8, 2002

(0-16-02 DW

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PATENT

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AMENDMENT

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Commissioner for Patents Washington, DC 20231

Technology Center 2100

Sir:

In response to the Office Action dated July 8, 2002, please amend the aboveidentified application as follows:

IN THE CLAIMS:

Please cancel claims 1 and 2 in their entirety without prejudice or disclaimer of the subject matter thereof.

Claims 3, 4 and 15 now read as follows:

3. (Amended) A semiconductor memory device comprising:

a plurality of input terminals for receiving write data, a control signal and an address signal; and

at least one output terminal, different in number from the input terminal(s) for receiving the write data, for outputting read data, wherein the input terminals are coupled

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